## **Definition of Electrode Potential from Density Functional + Implicit Solvation Theory**

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Electrode potential is a general concept, in electrochemistry, which governs the charge transfer reactions such as ion insertion/extraction and reduction-oxidation at electrode/solution interfaces; the electrode potential should be appropriately included in the computational model.<sup>1</sup> In this study, we consider how the standard hydrogen electrode (SHE) potential, which is the equilibrium potential of the charge transfer reaction of  $H^+/H_2$ , is theoretically evaluated.

We employed density functional theory (DFT) calculations combined with the effective screening medium (ESM) technique<sup>2</sup> + the reference interaction site method (RISM);<sup>3</sup> ESM-RISM formulation<sup>4</sup> makes it possible to simulate the electrode (+ reactive ions) and the solution based on quantum mechanics and implicit classical solvation model, respectively. Changing the chemical potential of electron,  $\mu_e$ , referenced to the inner potential  $\Phi_s$  at the bulk solution region, we compared the grand potentials  $\Omega$  for the following reaction:

 $H_3O^+$  (1M HCl aq.) +  $e^-$  (electrode M)  $\leftrightarrow 1/2$   $H_2$  (gas) +  $H_2O$  (1M HCl aq.)

In the presentation, we will compare the potential profile of metal/solution/vacuum region obtained from ESM-RISM and the first-principles molecular dynamics calculation using ESM.<sup>5</sup> We further discuss on the difference between  $\mu_e$ @SHE and the absolute SHE obtained by Trasatti.<sup>6</sup>

## References

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